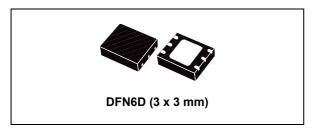


1.5 A, 1.5 MHz adjustable, step-down switching regulator

Datasheet - production data



Features

- Step-down current mode PWM (1.5 MHz) DC-DC converter
- 2% DC output voltage tolerance
- Internal soft-start for STARTUP current limitation and power on delay of 50 - 100 μs
- Typical efficiency: > 70% over all operating conditions
- 1.5 A output current capability
- Not switching quiescent current: max 2.5 mA over temperature range
- Switch V_{DS}: max. 350 mV at I_{SW} = 750 mA
- Uses tiny capacitors and inductors
- Available in DFN6D 3 x 3 mm package with exposed pad

Description

The ST1S03 is a step-down DC-DC converter optimized for powering a low voltage digital core in HDD applications and, generally, to replace the high current linear solution when the power dissipation may cause a high heating of the application environment. It provides up to 1.5 A over an input voltage range of 3 V to 16 V. A high switching frequency (1.5 MHz) allows the use of tiny surface-mount components: as well as the resistor divider to set the output voltage value, only an inductor, a Schottky diode and two capacitors are required. Besides, a low output ripple is guaranteed by the current mode PWM topology and by the use of low ESR SMD ceramic capacitors. The device is thermal protected and current limited to prevent damages due to an accidental short-circuit. The ST1S03 device is available in a DFN6D package.

Table 1. Device summary

Order code	Package	Packaging	
ST1S03PUR	DFN6D (3 x 3 mm)	Tape and reel	

Contents ST1S03

Contents

1	Diagram 3
2	Pin configuration
3	Maximum ratings
4	Electrical characteristics6
5	Application notes
6	Typical application 8
7	Typical performance characteristics
8	Package information
9	Revision history

ST1S03 Diagram

1 Diagram

 C_1

GND

R_{SENSE}

R_{SENSE}

R_{SENSE}

R_{SENSE}

V_C

Switch

V_C

INTERNAL REGULATOR

V_{IN_A}

Figure 1. Schematic diagram

CS21060

Pin configuration ST1S03

2 Pin configuration

Figure 2. Pin connections (top view)

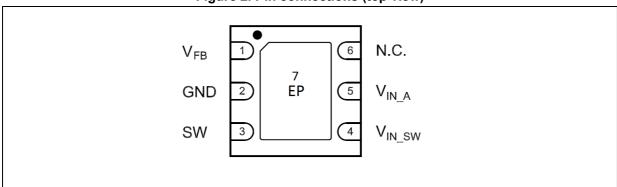


Table 2. Pin description

Pin no.	Symbol	Name and function	
1	V_{FB}	Voltage of feedback	
2	GND	System ground	
3	SW	Output of the internal power switch	
4	V _{IN_SW}	Power supply for the MOSFET switch	
5	V _{IN_A}	Power supply for the analog circuit	
6	N.C.	Not connected	
7	EP	Exposed pad should be connected to GND	

ST1S03 Maximum ratings

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{IN_SW}	Positive power supply voltage	-0.3 to 16	V
V _{IN_A}	Positive power supply voltage	-0.3 to 16	V
SWITCH voltage	Max voltage of output pin	-0.3 to 16	V
V _{FB}	Feedback voltage	2.5	V
I _{VFB}	Common mode input voltage	±1	mA
T _J	Max junction temperature	150	°C
T _{STG}	Storage temperature range	-25 to 150	°C
T _{LEAD}	Lead temperature (soldering) 10 s	300	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction case	10	°C/W
R _{thJA}	Thermal resistance junction ambient	55	°C/W

Electrical characteristics ST1S03

4 Electrical characteristics

Table 5. Electrical characteristics (V_{IN_SW} = V_{IN_A} = 5 V, C_I = 4.7 μ F, C_O = 22 μ F, L1 = 3.3 μ H, T_J = 0 to 125 °C, unless otherwise specified. Typical values are referred to 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
FB	Feedback voltage	I _O = 100 mA	784	800	816	mV	
I _{FB}	V _{FB} pin bias current				600	nA	
IQ	Quiescent current	No switching			2.5	mA	
Io	Output current	V _{IN} = 3 V to 16 V	1.5			Α	
I _{MIN}	Minimum output current		1			mA	
%V _O /ΔV _{IN}	Reference line regulation	V _{IN} = 3 V to 16 V		0.032	0.06	$\% V_{O}/\Delta V_{IN}$	
%V _O /∆I _O	Reference load regulation	I _O = 10 mA to 1.2 A		0.0014	0.003	% V _O /mA	
PWM f _S	PWM switching frequency ⁽¹⁾	V _{FB} = 0.8 V, T _A =25 °C		1.5	1.8	MHz	
D _{MAX}	Maximum duty cycle			87		%	
I _{SWL}	Switching current limitation		1.65			Α	
V _{DS}	Switch V _{DS}	I _{SW} = 750 mA		200	350	mV	
Е	Efficiency	I _O = 10 mA to 1.2 A	70			%	
T _{SHDN}	Thermal shutdown ⁽¹⁾		130	150		°C	
T _{HYS}	Thermal shutdown hysteresis ⁽¹⁾			15		°C	
$\Delta V_{O}/\Delta I_{O}$	Load transient response ⁽¹⁾	I_{O} = 100 mA to 700 mA t_{R} = t_{F} \geq 100 ns, T_{A} = 25 °C	-5	_	+5	% V _O	
$\Delta V_O / \Delta I_O at$ $I_O = short$	Short-circuit removal response ⁽¹⁾	I_O = 10 mA to short, T_A = 25 °C		_	+5	% V _O	

^{1.} Guaranteed by design, but not tested in production.



ST1S03 Application notes

5 Application notes

The ST1S03 is an adjustable current mode PWM step-down DC-DC converter with an internal 1.5 A power switch, housed in a 6-lead DFN 3 x 3 mm package.

It's a complete 1.5 A switching regulator with its internal compensation eliminating an additional component.

The constant frequency, current mode, PWM architecture and stable operation with ceramic capacitors results in a low, predictable output ripple. However, in order to keep the output regulated, the devices goes in pulse skipping mode when a very light load is required.

To clamp the error amplifier reference voltage, a soft-start control block generating a voltage ramp has been implemented. Besides an on-chip power on reset of $50 = 100 \,\mu s$ ensures the proper operation when switching on the power supply. Other circuits fitted to the device protection are the thermal shutdown blocks which turn off the regulator when the junction temperature exceeds 150 °C typically and the cycle-by-cycle current limiting that provides protection against shorted outputs.

Being the ST1S03 an adjustable regulator, the output voltage is determined by an external resistor divider. The desired value is given by the following equation:

$$V_{O} = V_{FB} [1 + R1 / R2]$$

To make the device working, only other four external components are required: a Schottky diode, an inductor and two capacitors. The chosen inductor must be able to not saturate at the peak current level. Besides, its value can be selected keeping in account that a large inductor value increases the efficiency at a low output current and reduces an output voltage ripple, while a smaller inductor can be chosen when it is important to reduce the package size and the total cost of the application. Finally, the ST1S03 device has been designed to work properly with the X5R or X7R SMD ceramic capacitors both at the input and at the output. This kind of capacitors, thanks to their very low series resistance (ESR), minimize the output voltage ripple. Other low ESR capacitors can be used according to the need of the application without invalidating the right functioning of the device. Due to the high switching frequency and peak current, it is important to optimize the application environment reducing the length of the PCB traces and placing all the external components near the device.



Typical application ST1S03

6 Typical application

 $V_{IN} \bigcirc$ N.C. V_{IN_A} ST1S03 $L_1 = 3.3 \mu H$ V_{IN_SW} $-\bigcirc$ V_{OUT} =1.2 V SW GND V_{FB} D_1 R₁ 25 KΩ C_2 R_2 50 Κ Ω $22\,\mu\mathrm{F}$ CS21050

Figure 3. Application circuits

7 Typical performance characteristics

(L1 = 3.3 μ H, C_I = 4.7 μ F, C_O = 22 μ F, unless otherwise specified).

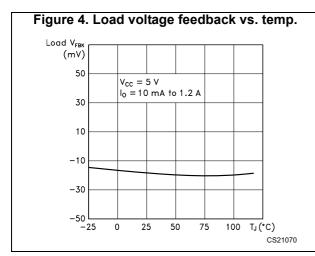


Figure 5. Voltage feedback vs. temperature

V_{FBK}
(mV)

850

V_{CC} = 5 V

I₀ = 10 mA

750

700

-25 0 25 50 75 100 T_J(*C)

CS21080

Figure 6. Line output voltage regulation vs. temperature

Line Vo (mV)

50

Vcc = 3 V to 16 V
Io = 10 mA

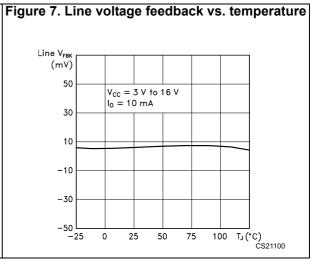
10

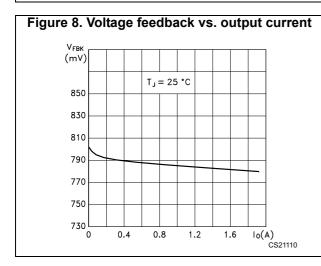
-10

-30

-50

-25
0
25
50
75
100
TJ (*C)
CS21090





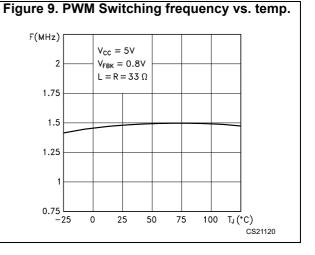




Figure 10. Quiescent current vs. temperature ΙQ (mA) $V_{CC} = 5 V$ 3.0 $V_{FBK} = 0.9 V$ (not switching) 2.5 2.25 2.0 1.75 1.5 1.25 1.0 <u></u> −25 100 T_J (°C) CS21130 0 25 50 75

Figure 12. Minimum operating voltage vs. output voltage

Vcc(V)

3.5

3

2.5

2

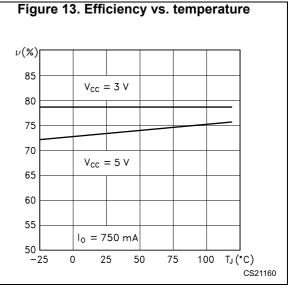
50

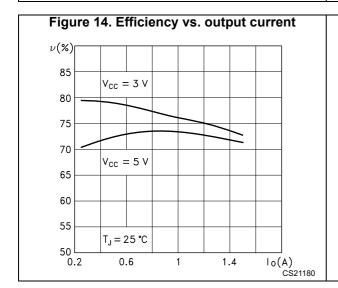
75

100

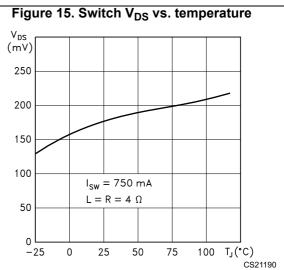
T_J (°C)

CS21150





25



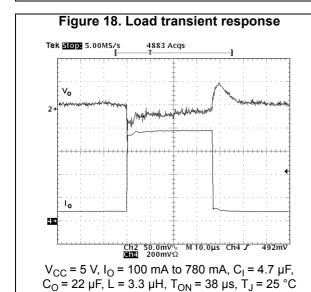
57

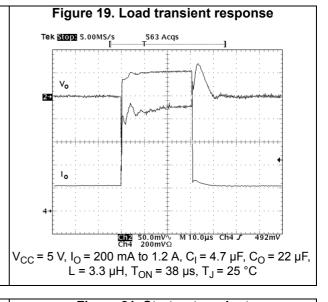
10/16

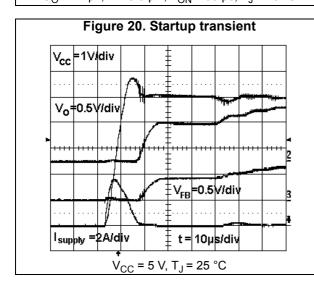
1.5

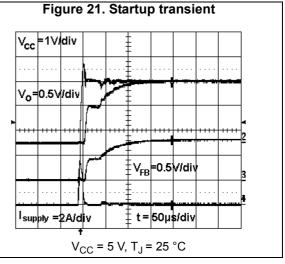
-25

Figure 17. Switch current limitation vs. temperature 1_{SW} (A) 3.5 3 2.5 2 $V_{CC} = 5 V$ $L = R = 1 \Omega$ 1.5 100 T_J(°C) CS21210 0 75 -2525 50







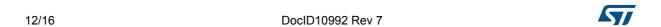


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Package information ST1S03

8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



ST1S03 Package information

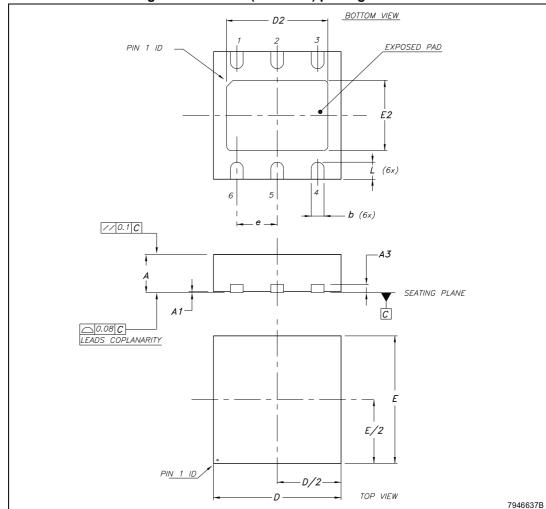


Figure 22. DFN6D (3 x 3 mm) package outline

Table 6. DFN6D (3 x 3 mm) package mechanical data

Symbol	Dimensions (mm)			Dimensions (inch)		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.80		1.00	0.031		0.039
A1	0	0.02	0.05	0	0.001	0.002
A3		0.20			0.008	
b	0.23		0.45	0.009		0.018
D	2.90	3.00	3.10	0.114	0.118	0.122
D2	2.23		2.50	0.088		0.098
Е	2.90	3.00	3.10	0.114	0.118	0.122
E2	1.50		1.75	0.059		0.069
е		0.95			0.037	
L	0.30	0.40	0.50	0.012	0.016	0.020

Package information ST1S03

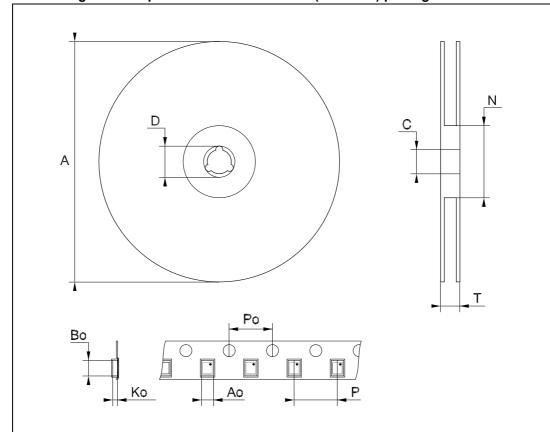


Figure 23. Tape and reel QFNxx/DFNxx (3 x 3 mm) package outline⁽¹⁾

1. Drawing is not in scale.

Table 7. Tape and reel QFNxx/DFNxx (3 x 3 mm) package mechanical data

Symbol	Di	imensions (m	m)	Dimensions (inch)		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			18.4			0.724
Ao		3.3			0.130	
Во		3.3			0.130	
Ko		1.1			0.043	
Ро		4			0.157	
Р		8			0.315	

ST1S03 Revision history

9 Revision history

Table 8. Document revision history

Date	Revision	Changes	
11-Nov-2004	1	First Release.	
08-Feb-2005	2	Maturity Change.	
03-Mar-2005	3	Mistake on Figure 1, T _J is changed 125 ==> 150°C on Table 3.	
13-Jul-2005	4	Add new package SO-8 exposed pad.	
29-Mar-2007	5	Package SO-8 removed.	
07-Mar-2008	6	Removed: package mechanical data DFN6.	
14-Nov-2014	7	Updated <i>Table 1: Device summary on page 1</i> (updated Packaging). Updated <i>Figure 2: Pin connections (top view) on page 4</i> (replaced by new figure). Updated <i>Table 2: Pin description on page 4</i> (added row 7). Updated <i>Section 8: Package information on page 12</i> (updated and added titles, updated ECOPACK text, reversed order of <i>Figure 22</i> and <i>Table 6</i> , <i>Figure 23</i> and <i>Table 7</i> , updated headings of <i>Table 6</i> and <i>Table 7</i>). Minor modifications throughout document.	

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